

IGBT MODULE (F series)

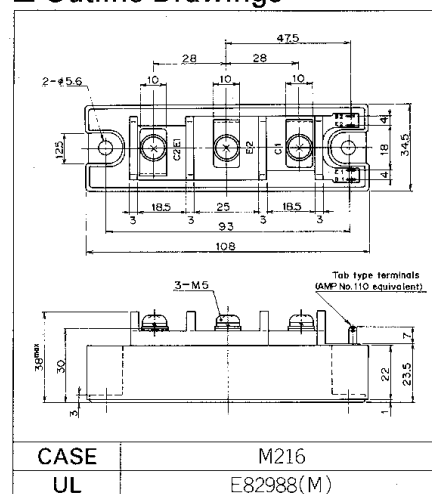
■ Features

- Low Saturation Voltage
- Voltage Drive
- Variety of Power Capacity Series

■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial Machines, such as Welding Machines

■ Outline Drawings



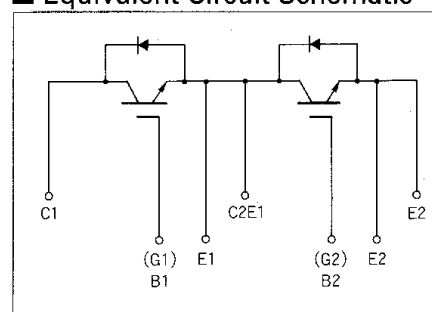
■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings

Items		Symbols	Ratings	Units
Collector-Emitter Voltage		V_{CES}	1200	V
Gate-Emitter Voltage		V_{GES}	± 20	V
Collector Current	Continuous	I_C	75	A
	1ms	$I_{C \text{ pulse}}$	150	
	Continuous	$-I_C$	75	
	1ms	$-I_{C \text{ pulse}}$	150	
Max. Power Dissipation		P_C	540	W
Operating Temperature		T_J	+150	$^{\circ}\text{C}$
Storage Temperature		T_{stg}	-40 to +125	$^{\circ}\text{C}$
Net. Weight			230	g
Isolation Voltage	AC. 1min.	V_{isol}	2500	V
Screw Torque		Mounting *1	3.5 [35]	N · m
		Terminals *1	3.5 [35]	(kg · cm)

*1 Recommendable Value 2.5 to 3.5 N•m [25 to 35 kg•cm] (M5)

■ Equivalent Circuit Schematic

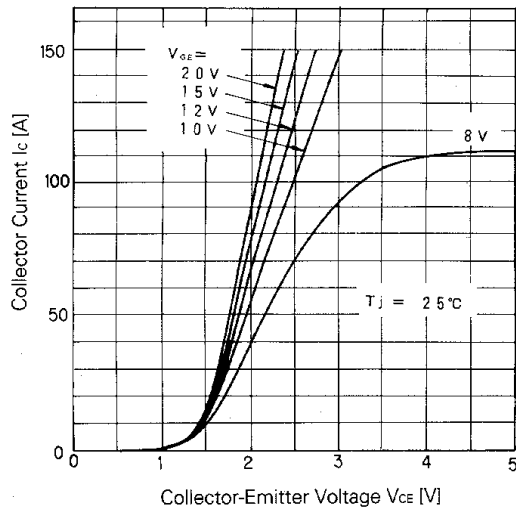


● Electrical Characteristics (T_c=25°C)

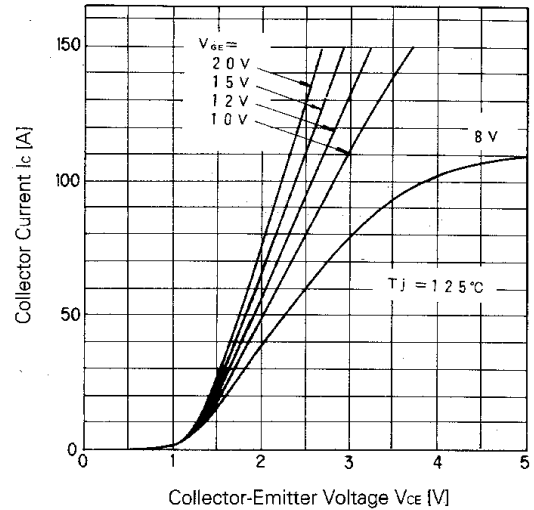
Items	Symbols	Test Conditions		Min.	Typ.	Max.	Units
Zero Gate Voltage Collector Current	ICES	VGE=0V VCE=1200V TJ=25°C				1.0	mA
		VGE=0V VCE=1200V TJ=125°C				—	mA
Gate-Emitter Leakage Current	IGES	VCE=0V VGE=±20V				100	nA
Gate-Emitter Threshold Voltage	VGE (th)	VCE=20V IC=100mA		3.0		6.0	V
Collector-Emitter Saturation Voltage	VCE (sat)	VGE=15V IC=100A				2.5	V
Input Capacitance	Cies	VGE=0V			13000		pF
Output Capacitance	Coes	VCE=10V			—		
Reverse Transfer Capacitance	Cres	f=1MHz			—		
Turn-on Time	ton	VCC=600V IC=100A	Resitive load			0.8	μs
	tr					0.6	
Turn-off Time	toff	VGE=±15V RG=9.1Ω	Inductive load			1.5	
	tf					1.0	
Diode Forward On-Voltage	VF	IF=100A, VGE=0V				2.5	V
Reverse Recovery Time	trr	IF=100A, -di/dt=300A/μs VGE=-10V				350	ns

● Thermal Characteristics

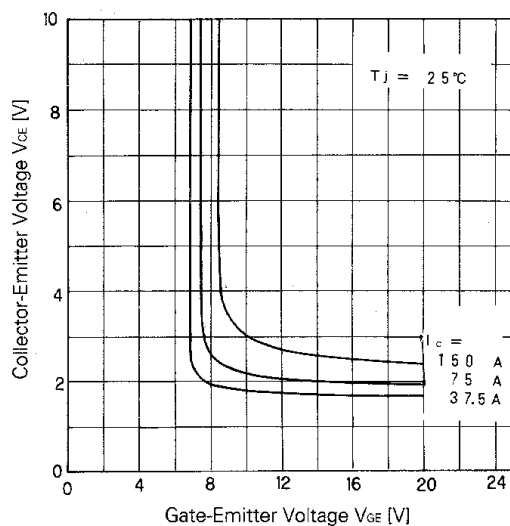
Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	R _{th(j-c)}	IGBT			0.231	°C/W
	R _{th(j-c)}	Diode			0.444	
	R _{th(c-f)}	With Thermal compound		0.05		



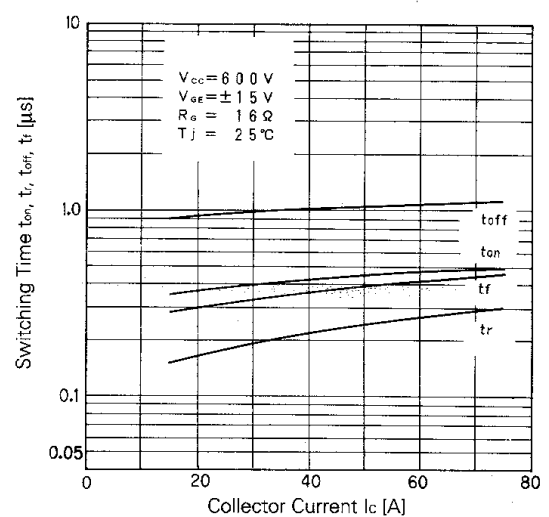
Collector Current vs. Collector-Emitter Voltage



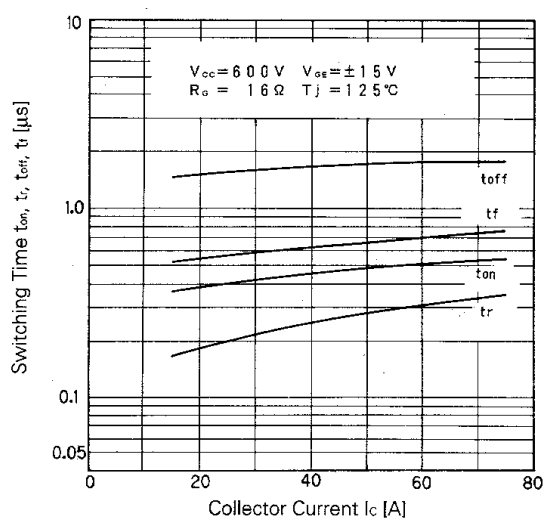
Collector Current vs. Collector-Emitter Voltage



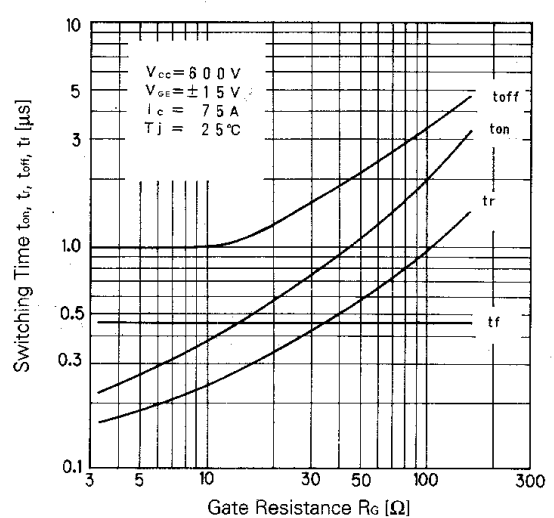
Collector-Emitter Voltage vs. Gate-Emitter Voltage



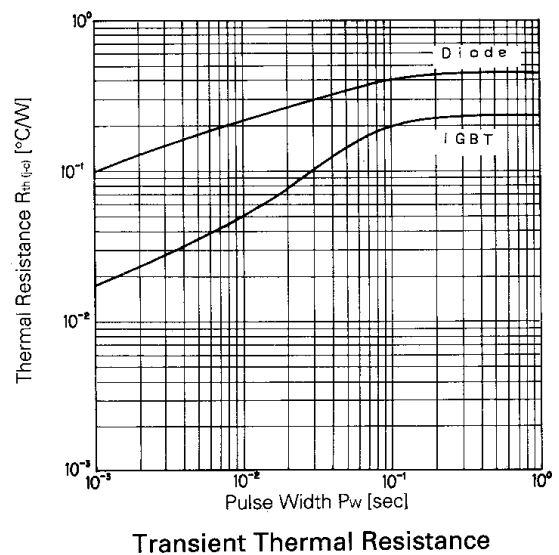
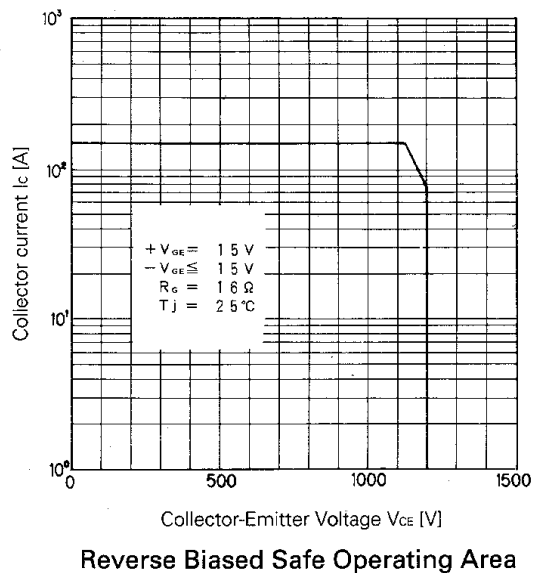
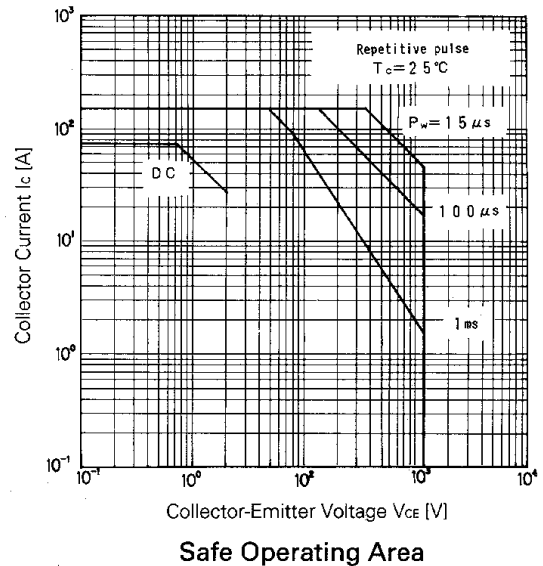
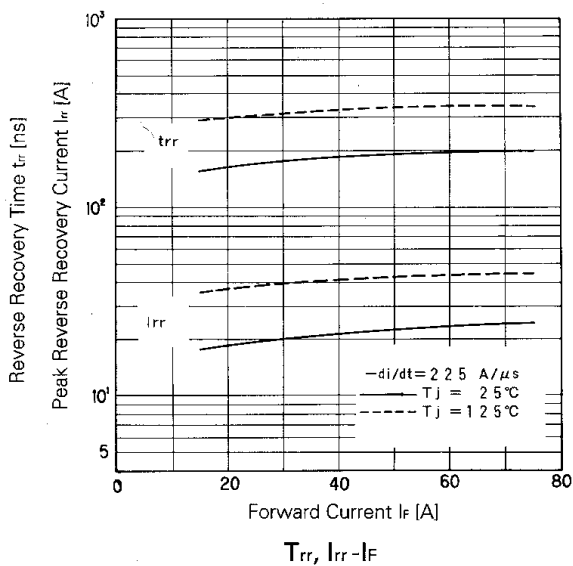
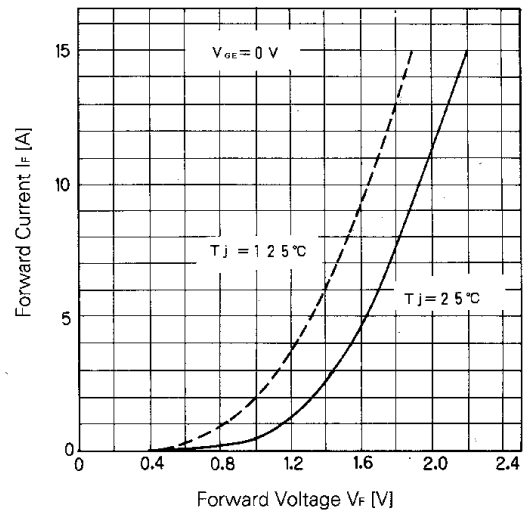
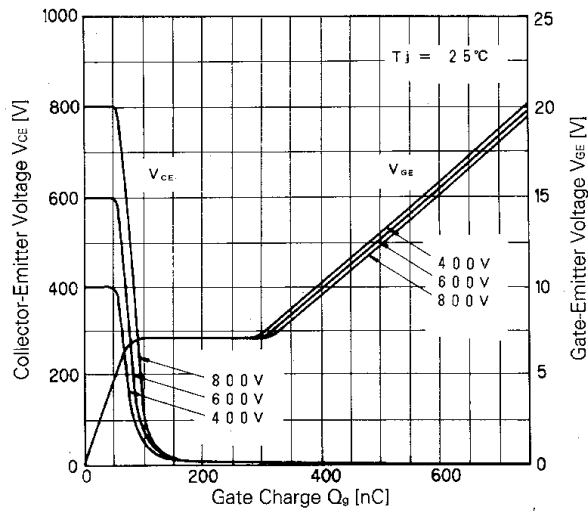
Switching Time



Switching Time



Switching Time-Gate Resistance



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